Final Program

2016 URSI Asia-Pacific Radio Science Conference **URSI AP-RASC 2016**

August 21 - 25, 2016 Grand Hilton Seoul Hotel, Seoul, Korea

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Program at a Glance



	Time	Room A (Emerald A)	Room B (Emerald B)	Room C (Diamond)	Room D (Convention A)	Room E (Convention B)	Room F (Convention C)	Room G (Convention D)	Room H (Convention E)	Room I (Crane)	Room J (Swan)	Room K (White Heron)		
	10:00~10:40	Opening Ceremony (Convention A~C, 4F, Convnetion Center, Grand Hilton Seoul Hotel)												
	10:40~11:00	Coffee Break												
	11:00~12:00		[General Lecture I] Nature Inspired Optimization Techniques in Modern Engineering: Let Darwin and the Bees Help Improve your Designs (Convention A~C, 4F, Convnetion Center, Grand Hilton Seoul Hotel)											
Aug. 22	12:00~13:30	Lunch												
(MON.)	13:30~15:30	[S-B14] Multiscale Multiphysics Techniques and Applications	[S-B12a] Novel Mathematical Methods in Electromagnetics (1)	[S-J1] New technology in Very Long Baseline Interferometry and Single Dishes	[S-K1a] Biological Effects of ENF (1)	SYP Special Session	[S-C3] Wireless Network	[S-G1] GPS/GNSS Monitoring of the lonosphere	[S-H1] Theory and Simulation of Waves in Plasma	[S-E1] Common-Mode Issues Related to Power Electronics	[S-D1] Microwave and THz Photonics	[S-F1] Wave Propagation and Scattering		
	15:30~16:00		Coffee Break											
	16:00~18:00	[S-B2] Reconfigurable Antennas and Miniaturized Antennas	[S-B12b] Novel Mathematical Methods in Electromagnetics (2)	[S-J2] Science and Technology of the Square Kilometer Array	[S-K1b] Biological Effects of EMF (2)	[C1] Spectrum Engineering Technology	[S-C4] Radio Localization Techniques	[S-G3] Radar Probing for the Ionospheric Variability	[S-H2] Generation and Characteristics of Waves in Space	[S-E2] Signal Integrity and EMI of Chip, Package, and PCB	[S-D3] Terahertz Electronics and Photonics	[S-F2a] Remote Sensing for Land and Sea (1)		

	Time	Room A (Emerald A)	Room B (Emerald B)	Room C (Diamond)	Room D (Convention A)	Room E (Convention B)	Room F (Convention C)	Room G (Convention D)	Room H (Convention E)	Room I (Crane)	Room J (Swan)	Room K (White Heron)	
	08:30~10:30	[S-B3] Groundwave Propagation Modeling, Simulation and Measurement	[S-B12c] Novel Mathematical Methods in Electromagnetics (3)	[S-J3] Science and Technology of Atacama Large Millimeter/Submillimeter Array	[S-K2a] Exposure Assessment and EMF Standards (1)		[S-C6] IoT and green Communications	[S-G2] lonospheric Density Variability in the Polar Region	(S-H3a) Radio Science for Space Weather (1)	[S-A1] EM Basic Metrology	[S-D2] Ultrafast Photonics	[S-F2b] Remote Sensing for Land and Sea (2)	
	10:30~11:00	Coffee Break											
	11:00~12:00	[General Lecture II] Electrodynamic Coupling Processes in the Solar-Terrestrial Environment (Convention A~C, 4F, Convnetion Center, Grand Hilton Seoul Hotel)											
Aug. 23 (Tue.)	12:00~13:30	Lunch											
()	13:30~15:30	[S-B4] Metamaterials & FSS	[S-B13a] Advances in Super- and High- Resolution Electromagnetic Imaging (1)	[S-J5a] Receivers for Radio Astronomy (1)	[S-K2b] Exposure Assessment and EMF Standards (2)	[S-K7] EM Biomedical Imaging	[S-C7] Massive MIMO and Millimeter Wave Communications	[S-G4] Satellite Probing for the lonospheric Variability	[S-H3b] Radio Science for Space Weather (2)	(S-A3) Antenna Related Metrology	[S-D4] Microwave and mm- wave Integrated Circuits	[S-F3a] Remote Sensing of the Atmosphere (1)	
	15:30~16:00	Coffee Break											
	16:00~18:00	[S-B5] Electromagnetic Field Theory	[S-B13b] Advances in Super- and High- Resolution Electromagnetic Imaging (2)	[B5] Fields and Waves Filter/ Resonator/Circuit	[S-K3a] Numerical Dosimetry (EMF Dosimetry) (1)	[S-KE] EMC in Biomedical Applications	[S-C8] Satellite and Terrestrial Networks	[S-G5] Observation of lonospheric Plasma Density Variation	[S-H4] Waves in Nuclear Fusion Plasmas and Laser- Plasma Accelerator	[A1] Antenna	[S-D5] High Power RF Devices and Circuits	[S-F3b] Remote Sensing of the Atmosphere (2)	
	18:00~20:00	Commission Business Meetings											

	Time	Room A (Emerald A)	Room B (Emerald B)	Room C (Diamond)	Room D (Convention A)	Room E (Convention B)	Room F (Convention C)	Room G (Convention D)	Room H (Convention E)	Room I (Crane)	Room J (Swan)	Room K (White Heron)	
	08:30~10:30	[S-B6] Wireless Power Transfer	[S-B1] Electrically Large Antennas	[S-J5b] Receivers for Radio Astronomy (2)	[S-K3b] Numerical Dosimetry (EMF Dosimetry) (2)	[S-E3] Modeling of Electromagnetic Immunity, EMS, and ESD	[C2] Radio Communication Systems and New Radio Service	[S-GH1] ULF/VLF Waves	[S-H5] Coherent Radiation Sources	[A2] Time and Frequency (Joint with ATF)	[S-D6] Low-energy Wireless Sensor Electronics	[S-F4a] Advanced Sensor and Radar Technology (1)	
	10:30~11:00	Coffee Break											
	11:00~12:00	[General Lecture III] 5G, Moving Steps Closer to Commercialization (Convention A–C, 4F, Convnetion Center, Grand Hilton Seoul Hotel)											
Aug. 24	12:00~13:30	Lunch											
(Wed.)	13:30~15:30	[S-B7] Computational Technique and EM Simulation	[B1] Fields and Waves 5G and MIMO Technology	[S-J6a] Science and Technology for Solar and Heliophysics (1)	(S-K4) EMFs for New Technologies	[S-E4] EMC Problems in Mobile Devices	[C3] Channel Model, Antenna and Propagation (1)	[S-GH2] Space Weather Impact and Mitigation Efforts	[S-HG1a] Effects of Wave- Particle Interactions in Earths Magnetosphere and Upper Atmosphere (1)	[A3] Material Measurement & Network Analysis	[S-D7] Photonic/ Electromagnetic Metamaterials and Metadevices	[S-F4b] Advanced Sensor and Radar Technology (2)	
	15:30~16:00	Coffee Break											
	16:00~18:00		Poster Session (Lobby, 3F, Convetion Center, Grand Hilton Seoul Hotel)										
	18:00~20:30	Banquet (Convention A~E, 4F, Convention Center, Grand Hilton Seoul Hotel)											

	Time	Room A (Emerald A)	Room B (Emerald B)	Room C (Diamond)	Room D (Convention A)	Room E (Convention B)	Room F (Convention C)	Room G (Convention D)	Room H (Convention E)	Room I (Crane)	Room J (Swan)	Room K (White Heron)	
	08:30~10:30	[S-B8] Negative Group Delay (NGD) Devices and Its Applications	(B2) Fields and Waves Metamaterials	[S-J6b] Science and Technology for Solar and Heliophysics (2)	[S-K5a] Biomedical Applications of EM Wave (1)	[S-E5] EMC and Information Security	[C4] Channel Model, Antenna and Propagation (2)	[G1] Radio Wave Propagation	(S-HG1b) Effects of Wave- Particle Interactions in Earths Magnetosphere and Upper Atmosphere (2)	[A4] Communication Related Metrology	[S-DBC1] Optical, Electrical and Optoelectronic Generation and Distribution of Microwave Signal	[S-F5] Radio Wave Propagation Aspects in Body Area Networks	
	10:30~11:00	Coffee Break											
Aug. 25	11:00~12:00	[General Lecture IV] Role of Electromagnetic Waves in Magnetic Fusion Plasma Research (Convention A~C, 4F, Convnetion Center, Grand Hilton Seoul Hotel)											
(Thu.)	12:00~13:30	Lunch											
	13:30~15:30	[S-B9a] Computational Techniques and EM Field Simulators (1)	[B3] Fields and Waves Frequency Selective Surface	[S-JDE4] Digital Technology for Radio Astronomy	[S-K5b] Biomedical Applications of EM Wave (2)	[S-EB] EMC Modeling and Techniques	[C5] Signal Processing, Algorism and Circuit	[G2] General lonospheric Studies (1)	[H1] Theory and Observation of Waves in the Earth's Magnetosphere		[D1] Optics and RF/THz Applications	[S-F6a] Remote Sensing of Precipitation (1)	
	15:30~16:00	Coffee Break											
	16:00~18:00	[S-B9b] Computational Techniques and EM Field Simulators (2)	[B4] Fields and Waves Wideband/Dualband Antenna	[J1] Five Hundred Meter Aperture Spherical Telescope (Fast)	[S-K6] Dosimetry for WBAN Antennas and Devices	[E1] Radio Interference and Spectrum	[C6] New Radio Service	[G3] General Ionospheric Studies (2)	[H2] Waves and Particles in Solar System: General		[D2] Energy Harvesting and other Electronic Components	[S-F6b] Remote Sensing of Precipitation (2)	

Session Title	[D2] Energy Harvesting and other Electronic Components
Date and Time	August 25 (Thu.) / 16:00~18:00
Room	Room J (Swan)
Session Chair	Sang-Min Han (Soonchunhyang University)

[D2-1]

High-Sensitivity and High-Efficiency 2.4-GHz RF Energy Harvester using SiP Technique

Ming-Che Yu and Chun-Hsing Li National Central University, Taiwan

[D2-2]

A Review on Recent Trend of High Efficieny Rectifiers for RF Energy Harvesting Applications

Zaffar Hayat Nawaz Khan¹, Danial Khan¹, Hamed Abbasizadeh¹, Sang-Yun Kim¹, Young-Jun Park¹, Kang-Yoon Lee¹, Seong-Ho Lee², and Seong-Chul Lee² ¹Sungkyunkwan University, Korea, ²Korea Electronics Technology Institute, Korea

[D2-3]

Properties of Stepped Impedance Resonator and Its Application in the Design of Chipless RFID Tag

Nijas C. M., Sajitha V. R., Jayakrishnan M. P., and Mohanan P. Cochin University of Science and Technology, India

[D2-4]

Study for Realization of Arbitrary Inductance Values using Distributed Elements and Capacitors

Jongsik Lim¹, Seok-Jae Lee¹, Dal Ahn¹, Sang-Min Han¹, Boram An², and Yongchae Jeong² ¹Soonchunhyang Univesity, Korea, ²Chonbuk National University, Korea

[D2-5]

Open Otto Chip as an SPR Pressure Transducer

J. O. Maciel Neto¹, Gustavo Oliveira Cavalcanti², Ignacio Llamas-Garro³, Jung-Mu Kim⁴, and Eduardo Fontana⁵ ¹Instituto Federal de Pernambuco, Brazil, ²Universidade de Pernambuco, Brazil, ³Centre Tecnològic de Telecomunicacions de Catalunya, Spain, ⁴Chonbuk National University, Korea, ⁵Universidade Federal de Pernambuco, Brazil

[D2-6]

A 35 dBm, 36.5% Efficiency Harmonic Tuned GaN Oscillator using Stepped Impedance Resonator Inhyun Kim, Sunghwan Park, Jung-Lin Woo, and Youngwoo Kwon Seoul National University, Korea

17:00~17:20

17:20~17:40

17:40~18:00

16:20~16:40

16:00~16:20

16:40~17:00

Study for Realization of Arbitrary Inductance Values using Distributed Elements and Capacitors

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Abstract—In design of microwave circuits, lots of arbitrary inductance values are required. In this paper, methods to realize arbitrary inductance values using transmission line with relatively high characteristic impedance and capacitor are discussed. The first design utilizes only transmission line, while the second method adopts a capacitor as well as the transmission line. In addition, the attached capacitor may have a fixed-value or variable capacitance. The related equations for calculating the equivalent inductance are induced with resultant inductance graph. It is well shown that arbitrary inductance values may be realized from the high impedance transmission lines with or without attached capacitor. In the second discussion, the obtained inductance is adjustable as the attached capacitance value is controlled.

Keywords—microwave inductors, distributed inductors, arbitrary inductors.

I. INTRODUCTION

In design of microwave circuits, lots of distributed elements such as chip resistors, inductors, and capacitors are required both directly within RF parts and indirectly in DC supplying networks. Even most of lumped elements are surface mount device (SMD) type and their size is normally very small, however, in practice, many designers suffer from the undesirable parasitic components due to the electrodes for soldering. To the worse, arbitrary element values are not exactly supported because chip element values are quantized as designated values by industrial standards such as the series of E12, E24, and so on. As for chip inductors, the same situation goes, so, in many cases, designers have to select the chip inductor which is the mostly near from the ideally required value and available in one's laboratory. This is one of main reasons of performance deviation between simulation and practical measurement. Especially, for multiple band applications, the deviation get worse at higher frequency bands needless to say at the fundamental or primary operating band [1-3].

In this work, methods for realizing arbitrary inductance values using distributed transmission line is discussed. The inductance values are realized using high impedance microstrip lines and varactor diodes. As results, it is possible **Boram An and **Yongchae Jeong

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to design the required arbitrary inductance value within a reasonable range and tune it finely by adjusting the characteristic impedance and electrical length of the microstrip line.

II. REALIZATION OF ARBITRARY INDUCTANCE VALUES USING HIGH INPEDANCE MICROSTRIP LINES

It is well known that the transmission line with a high characteristic impedance acts like a inductor at the operating frequency [4,5]. Fig. 1 shows the equivalence between the corresponding lumped inductor and the transmission line with a high impedance, Z_c , and electrical length, θ . If the inductance value is L_{eq} , there is a frequency, ω_o , when two input impedances of the lumped and distributed elements are equal to each other as shown in (1). So for an operating frequency(f_o) and pre-selected Z_c , an arbitrary inductance value can be realized theoretically by determining the proper θ . As an another way, if θ is chosen first, then proper Z_c can be calculated. However, the latter is not recommended because, in some cases, the calculated Z_c may express a capacitive property rather than an inductive element.



Fig. 1 Equivalence between an inductance and the transmission line with a high impedance, Z_c , and electrical length, θ . Input impedances of the (a)lumped inductor and (b)distributed element are equal at certain frequency.

$$Z_{in,L} = j\omega_o L_{eq}$$

$$Z_{in,D} = jZ_c \tan \theta$$
(1)

Taking " Z_c =100 Ω " at 1GHz as an example, a quasi-linear relation between inductance value and electrical length illustrated Fig. 2 is obtained. Summarily, it is possible to realize arbitrary inductance value by adjusting the electrical length of the high impedance microstrip line. In addition, in the simulation stage before the circuit realization, fine tuning can be applied to obtain a precisely required inductance.



Fig. 2 Calculated relation between inductance value and electrical length using equation (1) ($Z_c=100\Omega$ at 1 GHz).

III. CONTROLLABLE ARBITRARY INDUCTANCE VALUES [6]

One drawback of Fig. 2(b) is that it is impossible to change the equivalent inductance value once the circuit has been realized after fixing Z_c and θ . In order to overcome this problem, Fig. 3(a) can be proposed and improved as Fig. 3(b) [6]. Comparing Fig. 3(a) to Fig. 1(a), and equating the equivalent inductance value, then (3) is induced. This means a capacitor connected a high impedance transmission line can be seen as an equivalent inductor. Therefore if the capacitor is adjustable, then the resultant inductance is also controllable. This is the key advantage of Fig. 3(b). There are many ways to implement the variable capacitor such as adjustable capacitors and varactor diodes.

$$L_{eq} = \frac{\omega C Z_c^2 \tan \theta - Z_c}{\omega^2 C Z_c + \omega \tan \theta}$$
(2)



Fig. 3 Equivalent inductance circuits using transmission lines and capacitors (a)fixed capacitor (b)variable capacitor.[6]

As an example, when " $Z_c=100\Omega$ " and " $\theta=30^{\circ}$ " at 1GHz, one can get the adjustable equivalent inductance according to the variable capacitance as shown in Fig. 4. It is also understood that an arbitrary inductance value can be realized and controlled precisely by changing the connected capacitance as Fig. 3.



Fig. 4 Calculated relation between the equivalent inductance value and added capacitance using equation (2) ($Z_c=100\Omega$ and $\theta=30^\circ$ at 1 GHz).

IV. CONCLUSION

In this paper, study for realization of arbitrary inductance values has been discussed. The first method utilizes the transmission line with a relatively high characteristic impedance (Z_c) and electrical length (θ). Arbitrary equivalent inductance values are designed once Z_c and θ have been fixed previous.

In order to obtain the controllable arbitrary inductance, the second method adopts the high impedance transmission line with a capacitance value connected was discussed. By equating the proper relationship, the equivalent inductance has been induced. It was also shown that the obtained inductance value was adjustable as varying the attached capacitance.

ACKNOWLEDGMENT

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